



Vishay Semiconductors formerly General Semiconductor

DO-201AD 1.0 (25.4) Min. 0.210 (5.3) 0.190 (4.8) Dia. 0.375 (9.5) 0.285 (7.2) 1.0 (25.4) Min. 1.0 (25.4) Min.

Dimensions in inches and (millimeters)

Ultrafast Plastic Rectifier

Reverse Voltage 50 to 1000V Forward Current 3.0A

Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- · Glass passivated chip junction
- Low cost
- Ultrafast recovery time for high efficiency
- · Low forward voltage, high current capability
- Low leakage
- · High surge capability
- High temperature soldering guaranteed: 250°C, 0.375" (9.5mm) lead length for 10 seconds, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-201AD molded plastic body over

passivated chip

Terminals: Plated axial leads, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any **Weight:** 0.04 oz., 1.1 g

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbols	UF 5400	UF 5401	UF 5402	UF 5403	UF 5404	UF 5405	UF 5406	UF 5407	UF 5408	Units
Maximum repetitive peak reverse voltage	VRRM	50	100	200	300	400	500	600	800	1000	V
Maximum RMS voltage	VRMS	35	70	140	210	280	350	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	300	400	500	600	800	1000	V
Maximum average forward rectified current, 0.375" (9.5mm) lead length at T _A =55°C	I _{F(AV)}	3.0									А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at Ta=55°C	IFSM	150									А
Typical thermal resistance (1)	R⊕JA R⊕JL	20 8.5									°C/W
Operating junction and storage temperature range	TJ, TSTG	G -55 to +150									°C

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter		Symbols	UF 5400	UF 5401	UF 5402	UF 5403	UF 5404	UF 5405	UF 5406	UF 5407	UF 5408	Units
Maximum instantaneous forward voltag	e at 3.0A ⁽²⁾	VF	1.0					V				
	T _A = 25°C T _A =100°C	IR	75					0 200				
Maximum reverse recovery time at IF = 0.5A, IR = 1.0A, Irr = 0.25A	T _J = 25°C	t _{rr}	50				75				ns	
Typical junction capacitance at 4.0\	/, 1MHz	CJ			45				36			pF

Notes:

⁽¹⁾ Thermal resistance from junction to lead and from junction to ambient with 0.375" (9.5mm) lead length, both leads attached to heatsink

⁽²⁾ Pulse test: 300µs pulse width, 1% duty cycle

UF5400 thru UF5408

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Ratings and

Characteristic Curves (TA = 25°C unless otherwise noted)

Fig. 1 - Maximum Forward Current **Derating Curve** 3.0 Lead Length = 0.375" (9.5mm) Average Forward Rectified Current (A) 2.5 2.0 1.5 1.0 0.5 Resistive or Inductive Load 0 60 80 100 120 140 20 40 160 Ambient Temperature (°C)

Fig. 3 - Typical Instantaneous **Forward Characteristics**

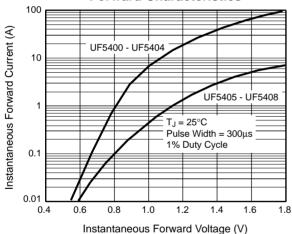


Fig. 5 - Typical Junction

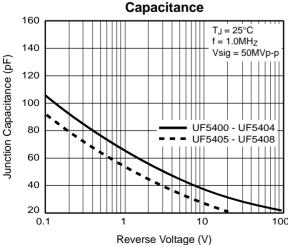


Fig. 2 – Maximum Non-Repetitive **Peak Forward Surge Current**

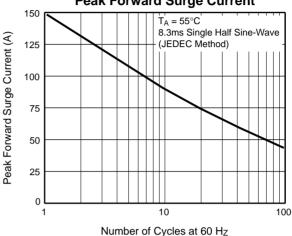
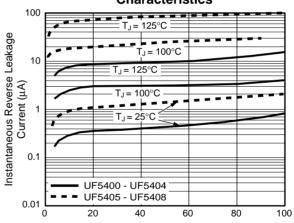


Fig. 4 - Typical Reverse Leakage Characteristics



Percent of Rated Peak Reverse Voltage (%)

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